TOSHIBA MULTI CHIP DISCRETE DEVICE

HN2E02F

Super High Speed Switching Application Audio Frequency Amplifier Application AM Amplifier Application

Q1

Low Forward Voltage Drop : $V_{F(3)}$ =0.98V(typ.) Fast Reverse Recovery Time : t_{rr} =1.6ns(typ.) Low Total Capacitance : C_T =0.5pF(typ.)

Q2

High Voltage : V_{CEO}=50V High Collector Current : I_C=150mA(max.)

Good h_{FE} Linearity : $h_{FE}(I_C=0.1\text{mA})/h_{FE}(I_C=2\text{mA}) = 0.95$

Q1 (Diode) : 1SS352 Equivalent
Q2 (Transistor) : 2SC4738 Equivalent

Q1 (Diode) Absolute Maximum Ratings (Ta = 25°C)

| Characteristic | Symbol | Rating | Unit |
|--------------------------------|-----------------|--------|-------------------|
| Maximum (peak) reverse voltage | V _{RM} | 85 | V |
| Reverse voltage | V _R | 80 | / <v< td=""></v<> |
| Maximum (peak) forward current | I _{FM} | 300 | mA |
| Average forward current | lo | 100 | mA |
| Surge current (10ms) | (FSM \ | 1 | A |

Weight: 0.015g (typ.)

Q2 (Transistor) Absolute Maximum Ratings (Ta = 25°C)

| | / / / ^ | | |
|---------------------------|--------------------|--------|------|
| Characteristic | Symbol | Rating | Unit |
| Collector-base voltage | V _{CBO} 〈 | (60//) | V |
| Collector-emitter voltage | V _{CEO} | 50 | V |
| Emitter-base voltage | V _{EBO} | 5 | V |
| Collector current | lc | 150 | mA |
| Base current | I _B > | 30 | mA |

Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

| Characteristic | \Diamond | Symbol | Rating | Unit |
|-----------------------------|--|------------------|---------|------|
| Collector power dissipation | () | PC* | 300 | mW |
| Junction temperature | \\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\ | Tj | 125 | °C |
| Storage temperature range | | T _{stg} | -55~125 | °C |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

^{*}Total rating: Power dissipation per element should not exceed 200mW per element.

Q1 (Diode) Electrical Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Circuit | Test Condition | Min | Тур. | Max | Unit |
|-----------------------|--------------------|-----------------|-------------------------------|-----|------|-----|------|
| Forward voltage | V _{F (1)} | _ | I _F = 1mA | - | 0.62 | - | ٧ |
| | V _{F (2)} | _ | I _F = 10mA | - | 0.75 | 1 | |
| | V _{F (3)} | _ | I _F = 100mA | _ | 0.98 | 1.2 | |
| Reverse current | I _{R (1)} | _ | V _R = 30V | 4 | - | 0.1 | μA |
| | I _{R (2)} | _ | V _R = 80V | | /2 | 0.5 | |
| Total capacitance | C _T | _ | V _R = 0, f = 1MHz |)) | 0.5 | - | pF |
| Reverse recovery time | t _{rr} | _ | I _F = 10mA (fig.1) | / | 1.6 | _ | ns |

Q2 (Transistor) Electrical Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Circuit | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------------|----------------------|-----------------|--|-----|----------|------|------|
| Collector cut-off current | I _{CBO} | _ | V _{CB} = 60V, I _E ≠ 0 | _ | | 100 | nA |
| Emitter cut-off current | I _{EBO} | _ | V _{EB} = 5V, I _C = 0 | - 0 | 17 | 100 | nA |
| DC current gain | h _{FE} * | _ | V _{CE} = 6V, I _C = 2mA | 120 | <u> </u> | 700 | |
| Collector-emitter saturation voltage | V _{CE(sat)} | _ | I _C =100mA, I _B =10mA | 7 | (0.17) | 0.25 | V |
| Transition Frequency | f _T | _ | V _{CE} = 10V, I _C =10mA | 60 | | _ | MHz |
| Collector Output Capacitance | C _{ob} | | V _{CB} = 10V, I _E = 0,f=1MHz | | 2.0 | _ | pF |

^{*} h_{FE} Rank Y(Y): 120~240, GR(G): 200~400,BL(L): 350~700

Marking

Equivalent Circuit (Top View)

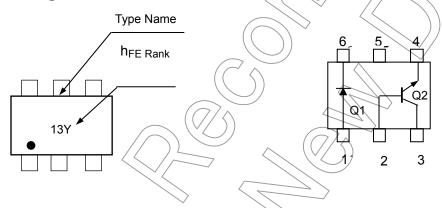
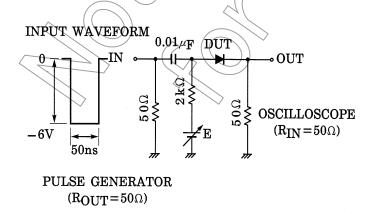
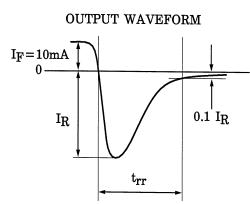


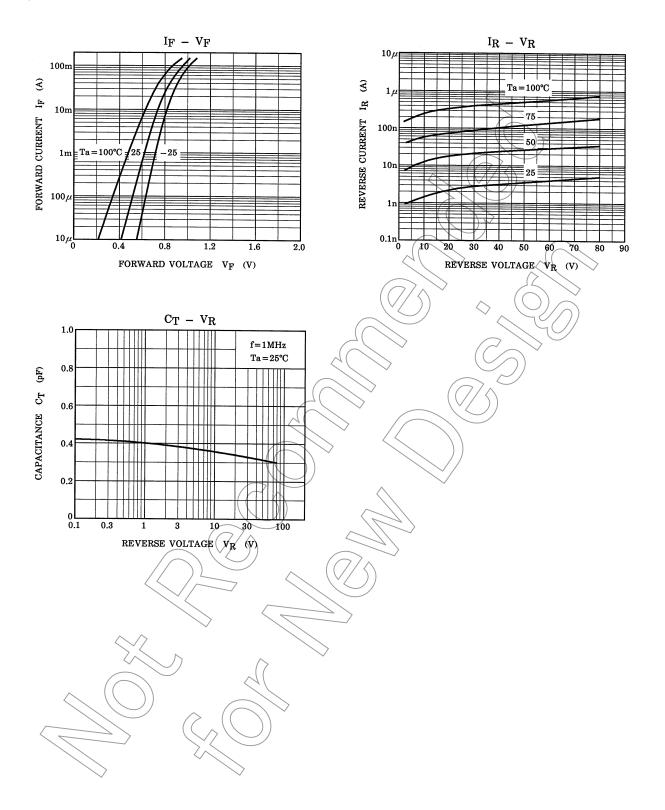
Fig. 1: Reverse Recovery Time (trr) Test Circuit





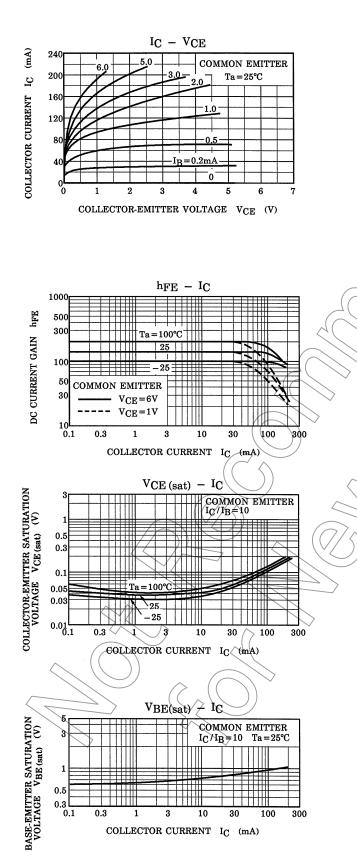
^() Marking Symbol

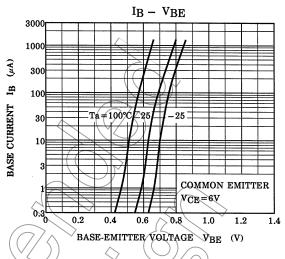
Q1

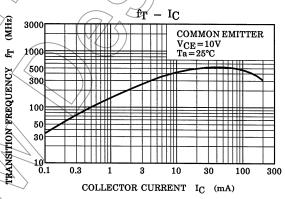


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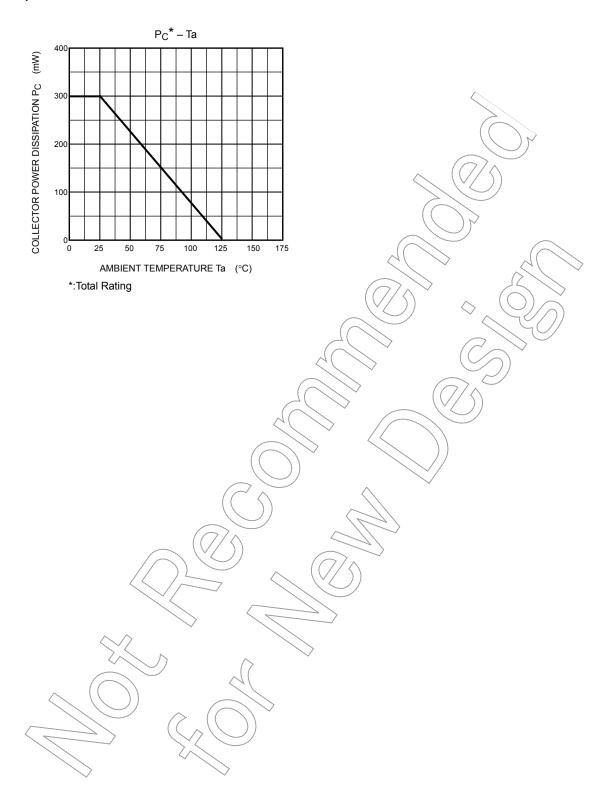
Q2







Q1, Q2 Common



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